

## A.F. SILICON PLANAR EPITAXIAL TRANSISTORS



N-P-N transistors in TO-18 metal envelopes with the collector connected to the case.

The BC107 is primarily intended for use in driver stages of audio amplifiers and in signal processing circuits of television receivers.

The BC108 is suitable for multitude of low-voltage applications e.g. driver stages or audio preamplifiers and in signal processing circuits of television receivers.

The BC109 is primarily intended for low-noise input stages in tape recorders, hi-fi amplifiers and other audio-frequency equipment.

## QUICK REFERENCE DATA

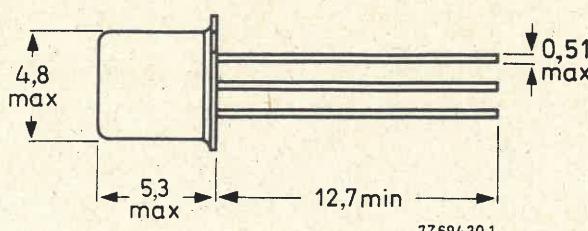
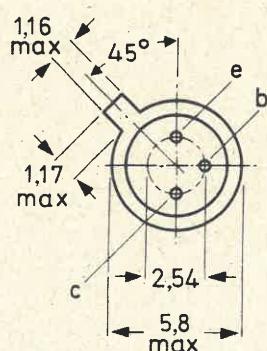
		BC107	BC108	BC109	
Collector-emitter voltage ( $V_{BE} = 0$ )	$V_{CES}$	max.	50	30	30 V
Collector-emitter voltage (open base)	$V_{CEO}$	max.	45	20	20 V
Collector current (peak value)	$I_{CM}$	max.	200	200	200 mA
Total power dissipation up to $T_{amb} = 25^\circ\text{C}$	$P_{tot}$	max.	300	300	300 mW
Junction temperature	$T_j$	max.	175	175	175 $^\circ\text{C}$
Small-signal current gain at $T_j = 25^\circ\text{C}$ $I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}; f = 1 \text{ kHz}$	$h_{fe}$	$>$ $<$	125 500	125 900	240 900
Transition frequency at $f = 35 \text{ MHz}$ $I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	$f_T$	typ.	300	300	300 MHz
Noise figure at $R_S = 2 \text{ k}\Omega$ $I_C = 200 \mu\text{A}; V_{CE} = 5 \text{ V}$ $f = 30 \text{ Hz to } 15 \text{ kHz}$	F	typ. $<$	— —	— —	1,4 dB 4,0 dB
$f = 1 \text{ kHz}; B = 200 \text{ Hz}$	F	typ.	2	2	1,2 dB

## MECHANICAL DATA

Dimensions in mm

Fig. 1 TO-18.

Collector connected  
to case



Accessories: 56246 (distance disc).

EATON Products approved to CECC 50 002-076/078.

BC107 to 109



Typical behaviour of collector current versus collector-emitter voltage

